## NSN 5961-01-247-1382

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**Fiig:** A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-247-1382 **Inclosure Material:** Metal **Overall Length:** 1.550 inches **Overall Height:** 0.300 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 700.0 collector-to-emitter, with voltage between base and emitter and 600.0 collector-to-emitter, substaining voltage, base open-circuited and 8.0 emitter to base, rms **Current Rating Per Characteristic:** 10.00 amperes source cutoff current and 7.00 amperes source cutoff current **Power Rating Per Characteristic:** 175.0 watts small-signal input power, common-collector absolute **Transfer Ratio:** 10.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 2 tab, solder lug and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No